

1 **IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

2 INVENTORSHIP BADDING, John V. et al.
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9 ATTORNEY DOCKET NO. SO03-P05
10 TITLE: SYNTHESIS OF GERMANIUM SULPHIDE AND RELATED
11 COMPOUNDS

12 **SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**
13 **PURSUANT TO 37 C.F.R. §§ 1.56, 1.97 AND 1.98**

14 This Supplemental Information Disclosure Statement is being filed in
15 compliance with 37 C.F.R. § 1.97(b)(1) (i.e., within three months of the filing date of
16 a national application other than a continued prosecution application under 37 C.F.R.
17 § 1.53(d)). Your attention is directed to the references listed on the attached Form
18 PTO-1449. No admission is made regarding whether the submitted references are
19 prior art.

20 Respectfully submitted,

21 John V. BADDING, Daniel William HEWAK,
22 and Chung-Che HUANG, assignors to the
23 University of Southampton, all Applicants

24 Dated: May 2, 2006

25 By: John S. Reid

John S. Reid
Attorney and agent for Applicant
Reg. No.: 36,369

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>				Complete if Known	
				Application Number	10/575,199
				Filing Date	10 APR. 2006
				First Named Inventor	BADDING, John V.
				Art Unit	
				Examiner Name	
Sheet	1	of	1	Attorney Docket Number	SO03-P05

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	A	D. Sheel and M. Pemble, "Atmospheric Pressure CVD Coatings on Glass", ICCG4 November 2002	✓
	B	Ohta T, Akahira N, Ohara S, Satoh I: "High-Density Phase Change Optical Recording", Optoelectronics 1995, 10:361-380	✓
	C	I. P. Kotsalas and C. Raptis, "High-temperature Structural Phase Transitions of GexS1-x Alloys Studied by Raman Spectroscopy", Physics Review B, Vol. 64, 11 SEP. 2001	✓
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1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.
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